

## CMOS Hex Buffer/Converter

The CD4050BMS is a non-inverting hex buffer and features logic level conversion using only one supply voltage (VCC). The input signal high level (VIH) can exceed the VCC supply voltage when this device is used for logic level conversions. This device is intended for use as CMOS to DTL/TTL converters and can drive directly two DTL/TTL loads. (VCC = 5V, VOL  $\leq$  0.4V, and IOL  $\geq$  3.3mA).

The CD4050BMS is designated as replacement for CD4010B. Because the CD4050BMS requires only one power supply, it is preferred over the CD4010B and should be used in place of the CD4010B in all inverter, current driver, or logic level conversion applications. In these applications the CD4050BMS is pin compatible with the CD4010B, and can be substituted for this device in existing as well as in new designs. Terminal No. 16 is not connected internally on the CD4050BMS, therefore, connection to this terminal is of no consequence to circuit operation. For applications not requiring high sink current or voltage conversion, the CD4069UB Hex Inverter is recommended.

The CD4050BMS is supplied in these 16 lead outline packages:

|                  |     |
|------------------|-----|
| Braze Seal DIP   | H4T |
| Frit Seal DIP    | H1E |
| Ceramic Flatpack | H3X |

## Features

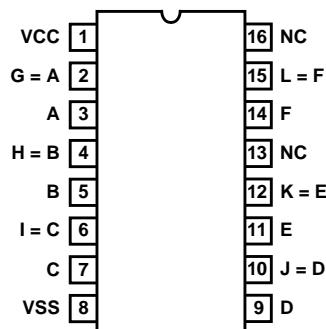
- High Voltage Type (20V Rating)
- Non-Inverting Type
- High Sink Current for Driving 2 TTL Loads
- High-to-Low Level Logic Conversion
- 100% Tested for Quiescent Current at 20V
- Maximum Input Current of 1 $\mu$ A at 18V Over Full Package Temperature Range; 100nA at 18V and +25°C
- 5V, 10V and 15V Parametric Ratings

## Applications

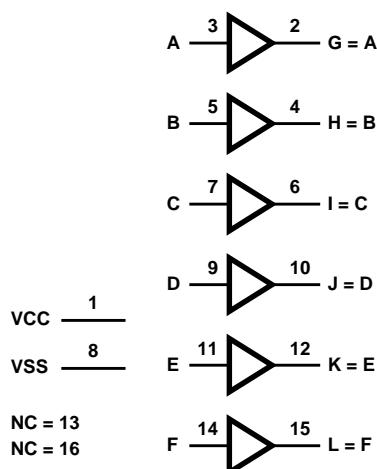
- CMOS to DTL/TTL Hex Converter
- CMOS Current "Sink" or "Source" Driver
- CMOS High-to-Low Logic Level Converter

## Pinout

CD4050BMS  
TOP VIEW



## Functional Diagram



## Schematic Diagram

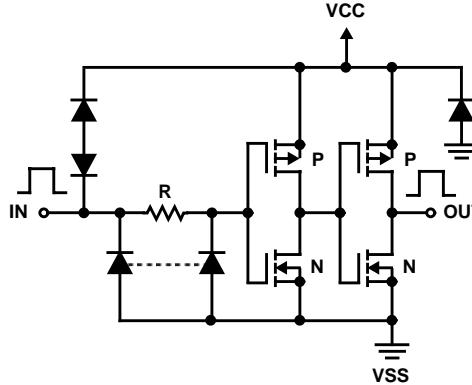


FIGURE 1. SCHEMATIC DIAGRAM, 1 OF 6 IDENTICAL UNITS

**Absolute Maximum Ratings**

|   |  |
|---|--|
| DC Supply Voltage Range, (VDD) . . . . .      | -0.5V to +20V  |
| (Voltage Referenced to VSS Terminals)         |  |
| Input Voltage Range, All Inputs . . . . .     | -0.5V to VDD +0.5V   |
| DC Input Current, Any One Input. . . . .      | $\pm 10\text{mA}$  |
| Operating Temperature Range . . . . .         | -55°C to +125°C<br>Package Types D, F, K, H  |
| Storage Temperature Range (TSTG). . . . .     | -65°C to +150°C  |
| Lead Temperature (During Soldering) . . . . . | +265°C<br>At Distance 1/16 ± 1/32 Inch (1.59mm ± 0.79mm) from case for 10s Maximum |

**Reliability Information**

|   |               |                                      |
|---|---------------|--------------------------------------|
| Thermal Resistance. . . . .                                 | $\theta_{ja}$ | $\theta_{jc}$                        |
| Ceramic DIP and FRIT Package . . . . .                      | 80°C/W        | 20°C/W                               |
| Flatpack Package. . . . .                                   | 70°C/W        | 20°C/W                               |
| Maximum Package Power Dissipation (PD) at +125°C            |               |                                      |
| For TA = -55°C to +100°C (Package Type D, F, K) . . . . .   |               | 500mW                                |
| For TA = +100°C to +125°C (Package Type D, F, K) . . . . .  |               | Derate Linearity at 12mW/°C to 200mW |
| Device Dissipation per Output Transistor. . . . .           |               | 100mW                                |
| For TA = Full Package Temperature Range (All Package Types) |               |                                      |
| Junction Temperature . . . . .                              |               | +175°C                               |

TABLE 1. DC ELECTRICAL PERFORMANCE CHARACTERISTICS

| PARAMETER                   | SYMBOL | CONDITIONS (NOTE 1)                | GROUP A SUBGROUPS | TEMPERATURE          | LIMITS      |             | UNITS |
|-----------------------------|--------|------------------------------------|-------------------|----------------------|-------------|-------------|-------|
|                             |        |                                    |                   |                      | MIN         | MAX         |       |
| Supply Current              | IDD    | VDD = 20V, VIN = VDD or GND        | 1                 | +25°C                | -           | 2           | µA    |
|                             |        |                                    | 2                 | +125°C               | -           | 200         | µA    |
|                             |        | VDD = 18V, VIN = VDD or GND        | 3                 | -55°C                | -           | 2           | µA    |
| Input Leakage Current       | IIL    | VIN = VDD or GND                   | 1                 | +25°C                | -100        | -           | nA    |
|                             |        |                                    | 2                 | +125°C               | -1000       | -           | nA    |
|                             |        | VDD = 18V                          | 3                 | -55°C                | -100        | -           | nA    |
| Input Leakage Current       | IIH    | VIN = VDD or GND                   | 1                 | +25°C                | -           | 100         | nA    |
|                             |        |                                    | 2                 | +125°C               | -           | 1000        | nA    |
|                             |        | VDD = 18V                          | 3                 | -55°C                | -           | 100         | nA    |
| Output Voltage              | VOL15  | VDD = 15V, No Load                 | 1, 2, 3           | +25°C, +125°C, -55°C | -           | 50          | mV    |
| Output Voltage              | VOH15  | VDD = 15V, No Load (Note 3)        | 1, 2, 3           | +25°C, +125°C, -55°C | 14.95       | -           | V     |
| Output Current (Sink)       | IOL4   | VDD = 4.5V, VOUT = 0.4V            | 1                 | +25°C                | 2.6         | -           | mA    |
| Output Current (Sink)       | IOL5   | VDD = 5V, VOUT = 0.4V              | 1                 | +25°C                | 3.2         | -           | mA    |
| Output Current (Sink)       | IOL10  | VDD = 10V, VOUT = 0.5V             | 1                 | +25°C                | 8.0         | -           | mA    |
| Output Current (Sink)       | IOL15  | VDD = 15V, VOUT = 1.5V             | 1                 | +25°C                | 24          | -           | mA    |
| Output Current (Source)     | IOH5A  | VDD = 5V, VOUT = 4.6V              | 1                 | +25°C                | -           | -0.8        | mA    |
| Output Current (Source)     | IOH5B  | VDD = 5V, VOUT = 2.5V              | 1                 | +25°C                | -           | -3.2        | mA    |
| Output Current (Source)     | IOH10  | VDD = 10V, VOUT = 9.5V             | 1                 | +25°C                | -           | -1.8        | mA    |
| Output Current (Source)     | IOH15  | VDD = 15V, VOUT = 13.5V            | 1                 | +25°C                | -           | -6.0        | mA    |
| N Threshold Voltage         | VNTH   | VDD = 10V, ISS = -10µA             | 1                 | +25°C                | -2.8        | -0.7        | V     |
| P Threshold Voltage         | VPTH   | VSS = 0V, IDD = 10µA               | 1                 | +25°C                | 0.7         | 2.8         | V     |
| Functional                  | F      | VDD = 2.8V, VIN = VDD or GND       | 7                 | +25°C                | VOH > VDD/2 | VOL < VDD/2 | V     |
|                             |        | VDD = 20V, VIN = VDD or GND        | 7                 | +25°C                |             |             |       |
|                             |        | VDD = 18V, VIN = VDD or GND        | 8A                | +125°C               |             |             |       |
|                             |        | VDD = 3V, VIN = VDD or GND         | 8B                | -55°C                |             |             |       |
| Input Voltage Low (Note 2)  | VIL    | VDD = 5V, VOH > 4.5V, VOL < 0.5V   | 1, 2, 3           | +25°C, +125°C, -55°C | -           | 1.5         | V     |
| Input Voltage High (Note 2) | VIH    | VDD = 5V, VOH > 4.5V, VOL < 0.5V   | 1, 2, 3           | +25°C, +125°C, -55°C | 3.5         | -           | V     |
| Input Voltage Low (Note 2)  | VIL    | VDD = 15V, VOH > 13.5V, VOL < 1.5V | 1, 2, 3           | +25°C, +125°C, -55°C | -           | 4           | V     |
| Input Voltage High (Note 2) | VIH    | VDD = 15V, VOH > 13.5V, VOL < 1.5V | 1, 2, 3           | +25°C, +125°C, -55°C | 11          | -           | V     |

NOTES: 1. All voltages referenced to device GND, 100% testing being implemented.

2. Go/No Go test with limits applied to inputs.

3. For accuracy, voltage is measured differentially to VDD. Limit is 0.050V max.

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**TABLE 2. AC ELECTRICAL PERFORMANCE CHARACTERISTICS**

| PARAMETER         | SYMBOL | CONDITIONS (NOTE 1, 2)     | GROUP A<br>SUBGROUPS | TEMPERATURE   | LIMITS |     | UNITS |
|-------------------|--------|----------------------------|----------------------|---------------|--------|-----|-------|
|                   |        |                            |                      |               | MIN    | MAX |       |
| Propagation Delay | TPHL   | VDD = 5V, VIN = VDD or GND | 9                    | +25°C         | -      | 110 | ns    |
|                   |        |                            | 10, 11               | +125°C, -55°C | -      | 149 | ns    |
| Propagation Delay | TPLH   | VDD = 5V, VIN = VDD or GND | 9                    | +25°C         | -      | 140 | ns    |
|                   |        |                            | 10, 11               | +125°C, -55°C | -      | 189 | ns    |
| Transition Time   | TTHL   | VDD = 5V, VIN = VDD or GND | 9                    | +25°C         | -      | 60  | ns    |
|                   |        |                            | 10, 11               | +125°C, -55°C | -      | 81  | ns    |
| Transition Time   | TTLH   | VDD = 5V, VIN = VDD or GND | 9                    | +25°C         | -      | 160 | ns    |
|                   |        |                            | 10, 11               | +125°C, -55°C | -      | 216 | ns    |

NOTES:

1. CL = 50pF, RL = 200K, Input TR, TF < 20ns.
2. -55°C and +125°C limits guaranteed, 100% testing being implemented.

**TABLE 3. ELECTRICAL PERFORMANCE CHARACTERISTICS**

| PARAMETER               | SYMBOL | CONDITIONS                  | NOTES | TEMPERATURE          | LIMITS |       | UNITS |
|-------------------------|--------|-----------------------------|-------|----------------------|--------|-------|-------|
|                         |        |                             |       |                      | MIN    | MAX   |       |
| Supply Current          | IDD    | VDD = 5V, VIN = VDD or GND  | 1, 2  | -55°C, +25°C         | -      | 1     | µA    |
|                         |        |                             |       | +125°C               | -      | 30    | µA    |
|                         |        | VDD = 10V, VIN = VDD or GND | 1, 2  | -55°C, +25°C         | -      | 2     | µA    |
|                         |        |                             |       | +125°C               | -      | 60    | µA    |
|                         |        | VDD = 15V, VIN = VDD or GND | 1, 2  | -55°C, +25°C         | -      | 2     | µA    |
|                         |        |                             |       | +125°C               | -      | 120   | µA    |
| Output Voltage          | VOL    | VDD = 5V, No Load           | 1, 2  | +25°C, +125°C, -55°C | -      | 50    | mV    |
| Output Voltage          | VOL    | VDD = 10V, No Load          | 1, 2  | +25°C, +125°C, -55°C | -      | 50    | mV    |
| Output Voltage          | VOH    | VDD = 5V, No Load           | 1, 2  | +25°C, +125°C, -55°C | 4.95   | -     | V     |
| Output Voltage          | VOH    | VDD = 10V, No Load          | 1, 2  | +25°C, +125°C, -55°C | 9.95   | -     | V     |
| Output Current (Sink)   | IOL4   | VDD = 4.5V, VOUT = 0.4V     | 1, 2  | +125°C               | 1.8    | -     | mA    |
|                         |        |                             |       | -55°C                | 3.3    | -     | mA    |
| Output Current (Sink)   | IOL5   | VDD = 5V, VOUT = 0.4V       | 1, 2  | +125°C               | 2.4    | -     | mA    |
|                         |        |                             |       | -55°C                | 4.0    | -     | mA    |
| Output Current (Sink)   | IOL10  | VDD = 10V, VOUT = 0.5V      | 1, 2  | +125°C               | 5.6    | -     | mA    |
|                         |        |                             |       | -55°C                | 10     | -     | mA    |
| Output Current (Sink)   | IOL15  | VDD = 15V, VOUT = 1.5V      | 1, 2  | +125°C               | 18     | -     | mA    |
|                         |        |                             |       | -55°C                | 26     | -     | mA    |
| Output Current (Source) | IOH5A  | VDD = 5V, VOUT = 4.6V       | 1, 2  | +125°C               | -      | -0.48 | mA    |
|                         |        |                             |       | -55°C                | -      | -0.81 | mA    |
| Output Current (Source) | IOH5B  | VDD = 5V, VOUT = 2.5V       | 1, 2  | +125°C               | -      | -1.55 | mA    |
|                         |        |                             |       | -55°C                | -      | -2.6  | mA    |
| Output Current (Source) | IOH10  | VDD = 10V, VOUT = 9.5V      | 1, 2  | +125°C               | -      | -1.18 | mA    |
|                         |        |                             |       | -55°C                | -      | -2.0  | mA    |
| Output Current (Source) | IOH15  | VDD = 15V, VOUT = 13.5V     | 1, 2  | +125°C               | -      | -3.1  | mA    |
|                         |        |                             |       | -55°C                | -      | -5.2  | mA    |

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**TABLE 3. ELECTRICAL PERFORMANCE CHARACTERISTICS (Continued)**

| PARAMETER          | SYMBOL | CONDITIONS                    | NOTES   | TEMPERATURE          | LIMITS |     | UNITS |
|--------------------|--------|-------------------------------|---------|----------------------|--------|-----|-------|
|                    |        |                               |         |                      | MIN    | MAX |       |
| Input Voltage Low  | VIL    | VDD = 10V, VOH > 9V, VOL < 1V | 1, 2    | +25°C, +125°C, -55°C | -      | 3   | V     |
| Input Voltage High | VIH    | VDD = 10V, VOH > 9V, VOL < 1V | 1, 2    | +25°C, +125°C, -55°C | +7     | -   | V     |
| Propagation Delay  | TPHL   | VIN = 10V, VDD = 5V           | 1, 2, 3 | +25°C                | -      | 100 | ns    |
|                    |        | VIN = 10V, VDD = 10V          | 1, 2, 3 | +25°C                | -      | 55  | ns    |
| Propagation Delay  | TPLH   | VIN = 10V, VDD = 5V           | 1, 2, 3 | +25°C                | -      | 90  | ns    |
|                    |        | VIN = 10V, VDD = 10V          | 1, 2, 3 | +25°C                | -      | 80  | ns    |
| Propagation Delay  | TPHL   | VIN = 15V, VDD = 5V           | 1, 2, 3 | +25°C                | -      | 100 | ns    |
|                    |        | VIN = 15V, VDD = 15V          | 1, 2, 3 | +25°C                | -      | 30  | ns    |
| Propagation Delay  | TPLH   | VIN = 15V, VDD = 5V           | 1, 2, 3 | +25°C                | -      | 80  | ns    |
|                    |        | VIN = 15V, VDD = 15V          | 1, 2, 3 | +25°C                | -      | 60  | ns    |
| Transition Time    | TTHL   | VDD = 10V, VIN = VDD OR GND   | 1, 2, 3 | +25°C                | -      | 40  | ns    |
|                    |        | VDD = 15V, VIN = VDD OR GND   | 1, 2, 3 | +25°C                | -      | 30  | ns    |
| Transition Time    | TTLH   | VDD = 10V, VIN = VDD OR GND   | 1, 2, 3 | +25°C                | -      | 80  | ns    |
|                    |        | VDD = 15V, VIN = VDD OR GND   | 1, 2, 3 | +25°C                | -      | 60  | ns    |
| Input Capacitance  | CIN    | Any Input                     | 1, 2    | +25°C                | -      | 7.5 | pF    |

NOTES:

1. All voltages referenced to device GND.
2. The parameters listed on Table 3 are controlled via design or process and are not directly tested. These parameters are characterized on initial design release and upon design changes which would affect these characteristics.
3. CL = 50pF, RL = 200K, Input TR, TF < 20ns.

**TABLE 4. POST IRRADIATION ELECTRICAL PERFORMANCE CHARACTERISTICS**

| PARAMETER                 | SYMBOL       | CONDITIONS                  | NOTES      | TEMPERATURE | LIMITS      |                    | UNITS |
|---------------------------|--------------|-----------------------------|------------|-------------|-------------|--------------------|-------|
|                           |              |                             |            |             | MIN         | MAX                |       |
| Supply Current            | IDD          | VDD = 20V, VIN = VDD or GND | 1, 4       | +25°C       | -           | 7.5                | µA    |
| N Threshold Voltage       | VNTH         | VDD = 10V, ISS = -10µA      | 1, 4       | +25°C       | -2.8        | -0.2               | V     |
| N Threshold Voltage Delta | ΔVTN         | VDD = 10V, ISS = -10µA      | 1, 4       | +25°C       | -           | ±1                 | V     |
| P Threshold Voltage       | VTP          | VSS = 0V, IDD = 10µA        | 1, 4       | +25°C       | 0.2         | 2.8                | V     |
| P Threshold Voltage Delta | ΔVTP         | VSS = 0V, IDD = 10µA        | 1, 4       | +25°C       | -           | ±1                 | V     |
| Functional                | F            | VDD = 18V, VIN = VDD or GND | 1          | +25°C       | VOH > VDD/2 | VOL < VDD/2        | V     |
|                           |              | VDD = 3V, VIN = VDD or GND  |            |             |             |                    |       |
| Propagation Delay Time    | TPHL<br>TPLH | VDD = 5V                    | 1, 2, 3, 4 | +25°C       | -           | 1.35 x +25°C Limit | ns    |

NOTES: 1. All voltages referenced to device GND.

3. See Table 2 for +25°C limit.

2. CL = 50pF, RL = 200K, Input TR, TF < 20ns.

4. Read and Record

**TABLE 5. BURN-IN AND LIFE TEST DELTA PARAMETERS +25°C**

| PARAMETER               | SYMBOL | DELTA LIMIT              |
|-------------------------|--------|--------------------------|
| Supply Current - MSI-1  | IDD    | ± 0.2µA                  |
| Output Current (Sink)   | IOL5   | ± 20% x Pre-Test Reading |
| Output Current (Source) | IOH5A  | ± 20% x Pre-Test Reading |

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**TABLE 6. APPLICABLE SUBGROUPS**

| CONFORMANCE GROUP             | MIL-STD-883 METHOD | GROUP A SUBGROUPS             | READ AND RECORD                       |
|-------------------------------|--------------------|-------------------------------|---------------------------------------|
| Initial Test (Pre Burn-In)    | 100% 5004          | 1, 7, 9                       | IDD, IOL5, IOH5A                      |
| Interim Test 1 (Post Burn-In) | 100% 5004          | 1, 7, 9                       | IDD, IOL5, IOH5A                      |
| Interim Test 2 (Post Burn-In) | 100% 5004          | 1, 7, 9                       | IDD, IOL5, IOH5A                      |
| PDA (Note 1)                  | 100% 5004          | 1, 7, 9, Deltas               |                                       |
| Interim Test 3 (Post Burn-In) | 100% 5004          | 1, 7, 9                       | IDD, IOL5, IOH5A                      |
| PDA (Note 1)                  | 100% 5004          | 1, 7, 9, Deltas               |                                       |
| Final Test                    | 100% 5004          | 2, 3, 8A, 8B, 10, 11          |                                       |
| Group A                       | Sample 5005        | 1, 2, 3, 7, 8A, 8B, 9, 10, 11 |                                       |
| Group B                       | Subgroup B-5       | Sample 5005                   | 1, 2, 3, 7, 8A, 8B, 9, 10, 11, Deltas |
|                               | Subgroup B-6       | Sample 5005                   | 1, 7, 9                               |
| Group D                       | Sample 5005        | 1, 2, 3, 8A, 8B, 9            | Subgroups 1, 2, 3                     |

NOTE: 1. 5% Parametric, 3% Functional; Cumulative for Static 1 and 2.

**TABLE 7. TOTAL DOSE IRRADIATION**

| CONFORMANCE GROUPS | MIL-STD-883 METHOD | TEST      |            | READ AND RECORD |            |
|--------------------|--------------------|-----------|------------|-----------------|------------|
|                    |                    | PRE-IRRAD | POST-IRRAD | PRE-IRRAD       | POST-IRRAD |
| Group E Subgroup 2 | 5005               | 1, 7, 9   | Table 4    | 1, 9            | Table 4    |

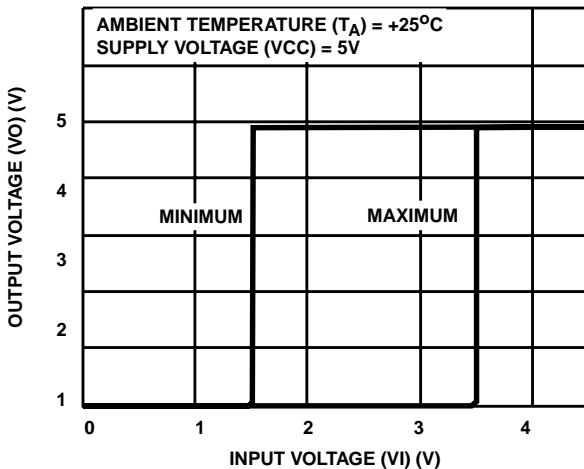
**TABLE 8. BURN-IN AND IRRADIATION TEST CONNECTIONS**

| FUNCTION                  | OPEN                        | GROUND           | VDD                       | 9V ± -0.5V          | OSCILLATOR         |       |
|---------------------------|-----------------------------|------------------|---------------------------|---------------------|--------------------|-------|
|                           |                             |                  |                           |                     | 50kHz              | 25kHz |
| Static Burn-In 1 (Note 1) | 2, 4, 6, 10, 12, 13, 15     | 3, 5, 7-9, 11-14 | 1, 16                     |                     |                    |       |
| Static Burn-In 2 (Note 1) | 2, 4, 6, 10, 12, 13, 15     | 8                | 1, 3, 5, 7, 9, 11, 14, 16 |                     |                    |       |
| Dynamic Burn-In (Note 3)  | 13                          | 8                | 1, 16                     | 2, 4, 6, 10, 12, 15 | 3, 5, 7, 9, 11, 14 |       |
| Irradiation (Note 2)      | 2, 4, 6, 10, 12, 13, 15, 16 | 8                | 1, 3, 5, 7, 9, 11, 14     |                     |                    |       |

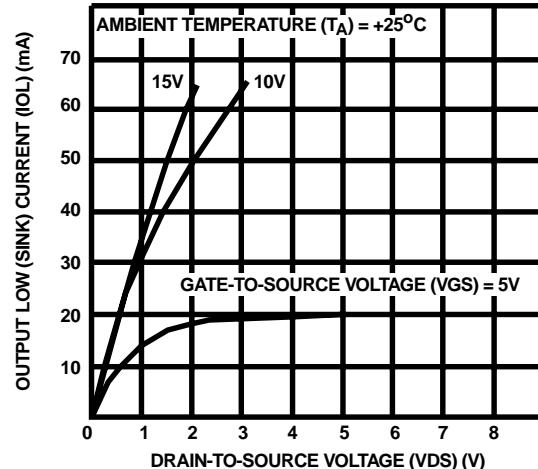
NOTES:

1. Each pin except pin 1, pin 16, and GND will have a series resistor of  $10K \pm 5\%$ , VDD =  $18V \pm 0.5V$
2. Each pin except pin 1, pin 16, and GND will have a series resistor of  $47K \pm 5\%$ ; Group E, Subgroup 2, sample size is 4 dice/wafer, 0 failures, VDD =  $10V \pm 0.5V$
3. Each pin except pin 1, pin 16, and GND will have a series resistor of  $4.75K \pm 5\%$ , VDD =  $10V \pm 0.5V$

## Typical Performance Characteristics



**FIGURE 2. MINIMUM AND MAXIMUM VOLTAGE TRANSFER CHARACTERISTICS**



**FIGURE 3. TYPICAL OUTPUT LOW (SINK) CURRENT CHARACTERISTICS**

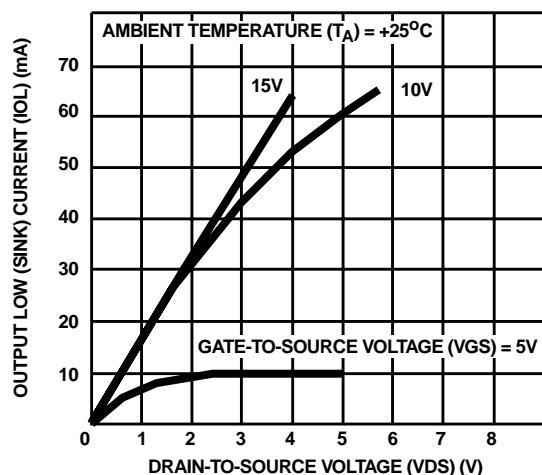
**Typical Performance Characteristics** (Continued)

FIGURE 4. MINIMUM OUTPUT LOW (SINK) CURRENT DRAIN CHARACTERISTICS

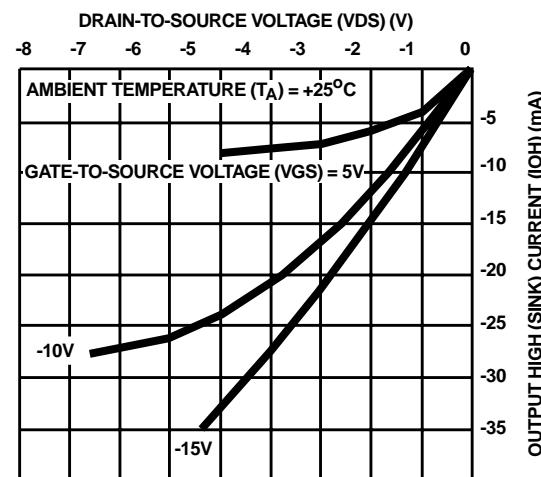


FIGURE 5. TYPICAL OUTPUT HIGH (SOURCE) CURRENT CHARACTERISTICS

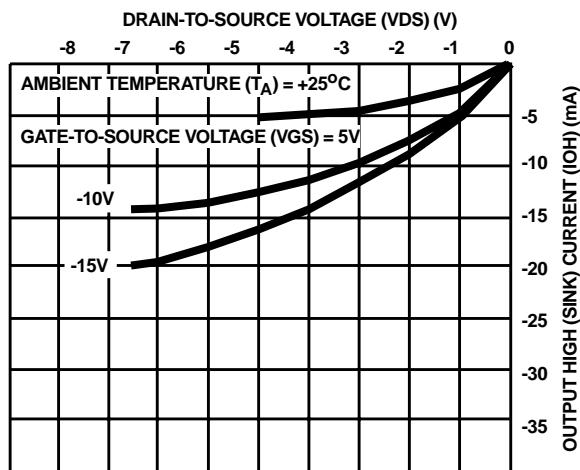


FIGURE 6. MINIMUM OUTPUT HIGH (SOURCE) CURRENT CHARACTERISTICS

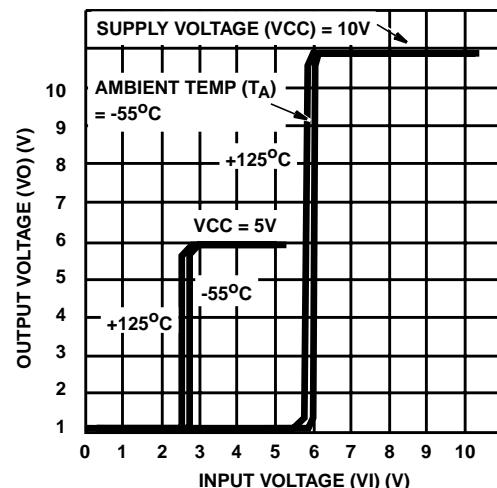


FIGURE 7. TYPICAL VOLTAGE TRANSFER CHARACTERISTICS AS A FUNCTION OF TEMPERATURE

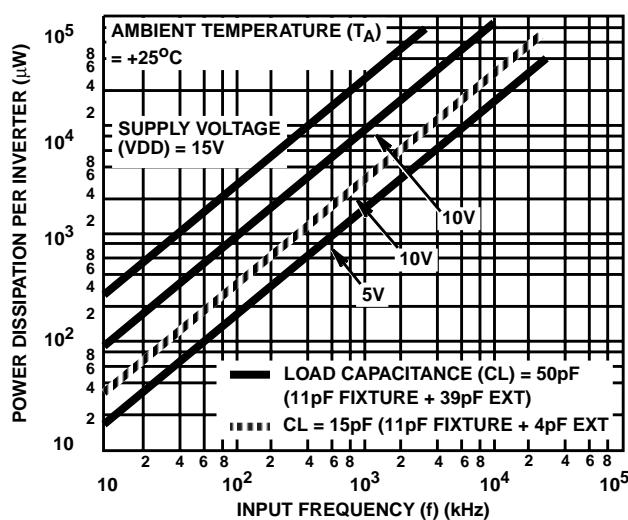


FIGURE 8. TYPICAL POWER DISSIPATION VS FREQUENCY CHARACTERISTICS

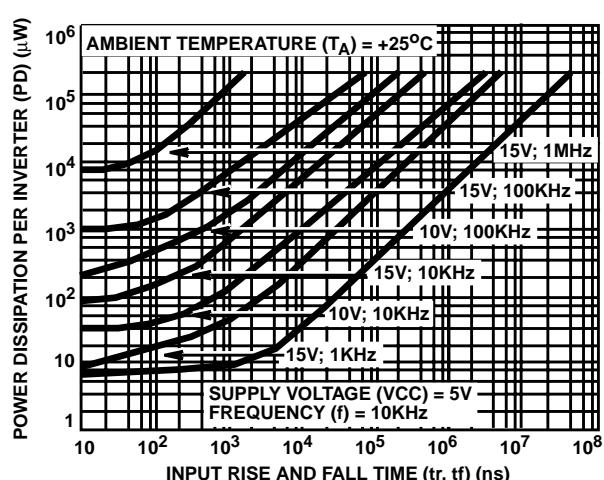
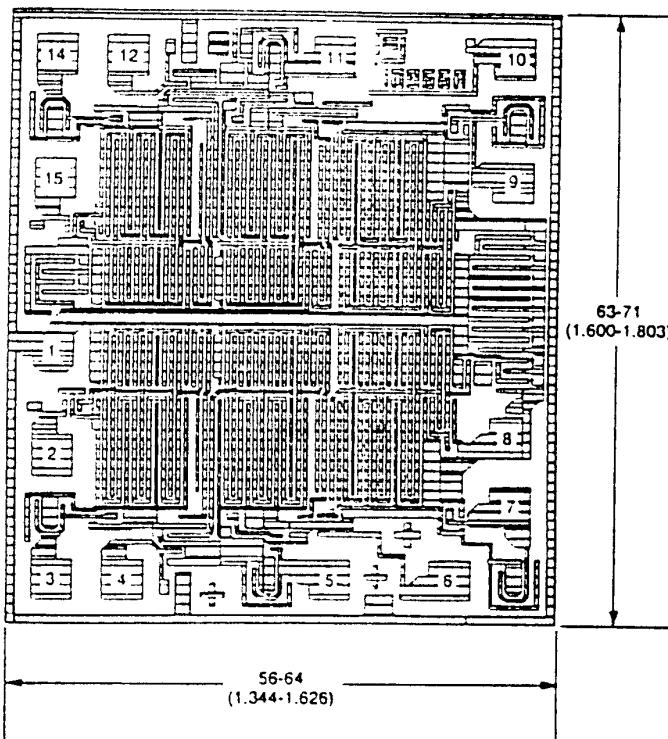


FIGURE 9. TYPICAL POWER DISSIPATION VS INPUT RISE AND FALL TIMES PER INVERTER

**Chip Dimensions and Pad Layout**

Dimensions in parenthesis are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils ( $10^{-3}$  inch).

**METALLIZATION:** Thickness:  $11\text{k}\text{\AA}$  –  $14\text{k}\text{\AA}$ , AL.

**PASSIVATION:**  $10.4\text{k}\text{\AA}$  -  $15.6\text{k}\text{\AA}$ , Silane

**BOND PADS:** 0.004 inches X 0.004 inches MIN

**DIE THICKNESS:** 0.0198 inches - 0.0218 inches

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